Features

- Fast Read Access Time 90 ns
- Dual Voltage Range Operation
 - Unregulated Battery Power Supply Range, 2.7V to 3.6V or Standard 5V \pm 10% Supply Range
- Pin Compatible with JEDEC Standard AT27C1024
- Low Power CMOS Operation
 - 20 µA max. (less than 1 µA typical) Standby for V_{cc} = 3.6V
 - 36 mW max. Active at 5 MHz for V_{cc} = 3.6V
- JEDEC Standard Surface Mount Packages
 - 44-Lead PLCC
 - 40-Lead VSOP (10 x 14mm)
- High Reliability CMOS Technology
 - 2,000V ESD Protection
 - 200 mA Latchup Immunity
- Rapid™ Programming Algorithm 100 μs/word (typical)
- CMOS and TTL Compatible Inputs and Outputs
- JEDEC Standard for LVTTL and LVBO
- Integrated Product Identification Code
- Commercial and Industrial Temperature Ranges

Description

The AT27BV1024 is a high performance, low power, low voltage 1,048,576-bit onetime programmable read only memory (OTP EPROM) organized as 64K by 16 bits. It requires only one supply in the range of 2.7V to 3.6V in normal read mode operation. The by-16 organization makes this part ideal for portable and handheld 16- and 32-bit microprocessor based systems using either regulated or unregulated battery power.



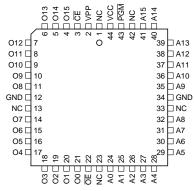
1-Megabit (64K x 16) Unregulated *Battery-Voltage*[™] High-Speed OTP EPROM

AT27BV1024

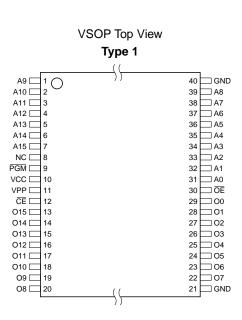
Pin Configurations

Pin Nam	ne	Function
A0 - A15	5	Addresses
00 - 01	5	Outputs
CE		Chip Enable
OE		Output Enable
PGM		Program Strobe
NC		No Connect
Note: E	Both GN	ND pins must be connected

PLCC Top View



Note: PLCC Package Pins 1 and 23 are DON'T CONNECT.



(continued)

Rev. 0631B-10/98





Atmel's innovative design techniques provide fast speeds that rival 5V parts while keeping the low power consumption of a 3V supply. At $V_{CC} = 2.7V$, any word can be accessed in less than 120 ns. With a typical power dissipation of only 18 mW at 5 MHz and $V_{CC} = 3V$, the AT27BV1024 consumes less than one fifth the power of a standard 5V EPROM.

Standby mode supply current is typically less than 1 μ A at 3V. The AT27BV1024 simplifies system design and stretches battery lifetime even further by eliminating the need for power supply regulation.

The AT27BV1024 is available in industry standard JEDECapproved one-time programmable (OTP) plastic PLCC and VSOP packages. All devices feature two-line control (\overline{CE} , \overline{OE}) to give designers the flexibility to prevent bus contention.

The AT27BV1024 operating with V_{CC} at 3.0V produces TTL level outputs that are compatible with standard TTL logic devices operating at V_{CC} = 5.0V. At V_{CC} = 2.7V, the part is compatible with JEDEC approved low voltage battery operation (LVBO) interface specifications. The device is also capable of standard 5-volt operation making it ideally suited for dual supply range systems or card products that are pluggable in both 3-volt and 5-volt hosts.

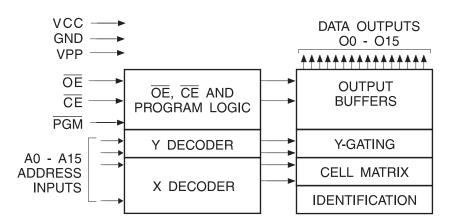
Atmel's AT27BV1024 has additional features to ensure high quality and efficient production use. The Rapid[™] Pro-

gramming Algorithm reduces the time required to program the part and guarantees reliable programming. Programming time is typically only 100 μ s/word. The Integrated Product Identification Code electronically identifies the device and manufacturer. This feature is used by industry standard programming equipment to select the proper programming algorithms and voltages. The AT27BV1024 programs exactly the same way as a standard 5V AT27C1024 and uses the same programming equipment.

System Considerations

Switching between active and standby conditions via the Chip Enable pin may produce transient voltage excursions. Unless accommodated by the system design, these transients may exceed data sheet limits, resulting in device non-conformance. At a minimum, a 0.1 μ F high frequency, low inherent inductance, ceramic capacitor should be utilized for each device. This capacitor should be connected between the V_{CC} and Ground terminals of the device, as close to the device as possible. Additionally, to stabilize the supply voltage level on printed circuit boards with large EPROM arrays, a 4.7 μ F bulk electrolytic capacitor should be utilized, again connected between the V_{CC} and Ground terminals. This capacitor should be positioned as close as possible to the point where the power supply is connected to the array.

Block Diagram



Absolute Maximum Ratings*

Temperature Under Bias55°C to +125°	°C
Storage Temperature65°C to +150°	°C
Voltage on Any Pin with Respect to Ground2.0V to +7.0V	(1)
Voltage on A9 with Respect to Ground2.0V to +14.0V	(1)
V _{PP} Supply Voltage with Respect to Ground2.0V to +14.0V	r(1)

*NOTICE: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability

Note: 1. Minimum voltage is -0.6V dc which may undershoot to -2.0V for pulses of less than 20 ns. Maximum output pin voltage is V_{CC} + 0.75V dc which may overshoot to +7.0V for pulses of less than 20 ns.

Operating Modes

Mode \ Pin	CE	OE	PGM	Ai	V _{PP}	V _{cc}	Outputs
Read ⁽²⁾	V _{IL}	V _{IL}	X ⁽¹⁾	Ai	Х	V _{CC} ⁽²⁾	D _{OUT}
Output Disable ⁽²⁾	Х	V _{IH}	Х	X	Х	V _{CC} ⁽²⁾	High Z
Standby ⁽²⁾	V _{IH}	Х	Х	X	X ⁽⁵⁾	V _{CC} ⁽²⁾	High Z
Rapid Program ⁽³⁾	V _{IL}	V _{IH}	V _{IL}	Ai	V _{PP}	V _{CC} ⁽³⁾	D _{IN}
PGM Verify ⁽³⁾	V _{IL}	V _{IL}	V _{IH}	Ai	V _{PP}	V _{CC} ⁽³⁾	D _{OUT}
PGM Inhibit ⁽³⁾	V _{IH}	Х	Х	Х	V _{PP}	V _{CC} ⁽³⁾	High Z
Product Identification ⁽³⁾⁽⁵⁾	V _{IL}	V _{IL}	х	$A9 = V_{H}^{(4)}$ $A0 = V_{IH} \text{ or } V_{IL}$ $A1 - A15 = V_{IL}$	V _{cc}	V _{CC} ⁽³⁾	Identification Code

Notes: 1. X can be $V_{\text{IL}} \text{ or } V_{\text{IH}}.$

- 2. Read, output disable, and standby modes require, 2.7V \leq V_{CC} \leq 3.6V, or 4.5V \leq V_{CC} \leq 5.5V.
- 3. Refer to Programming Characteristics. Programming modes require V_{CC} = 6.5V.
- 4. $V_{H} = 12.0 \pm 0.5 V.$
- 5. Two identifier words may be selected. All Ai inputs are held low (V_{IL}) , except A9 which is set to V_H and A0 which is toggled low (V_{IL}) to select the Manufacturer's Identification word and high (V_{IH}) to select the Device Code word.





DC and AC Operating Conditions for Read Operation

		AT27BV1024-90	AT27BV1024-12	AT27BV1024-15
Operating	Com.	0°C - 70°C	0°C - 70°C	0°C - 70°C
Temperature (Case)	Ind.	-40°C - 85°C	-40°C - 85°C	-40°C - 85°C
		2.7V to 3.6V	2.7V to 3.6V	2.7V to 3.6V
V _{CC} Power Supply		5V ± 10%	5V ± 10%	5V ± 10%

DC and Operating Characteristics for Read Operation

Symbol	Parameter	Condition	Min	Max	Units
V _{CC} = 2.7V	to 3.6V				
ILI	Input Load Current	$V_{IN} = 0V$ to V_{CC}		±1	μΑ
I _{LO}	Output Leakage Current	$V_{OUT} = 0V$ to V_{CC}		±5	μΑ
I _{PP1} ⁽²⁾	V _{PP} ⁽¹⁾ Read/Standby Current	$V_{PP} = V_{CC}$		10	μA
) ((1) Otra II. O marti	I_{SB1} (CMOS), $\overline{CE} = V_{CC} \pm 0.3V$		20	μA
I _{SB}	V _{CC} ⁽¹⁾ Standby Current	I_{SB2} (TTL), \overline{CE} = 2.0 to V_{CC} + 0.5V		100	μΑ
I _{cc}	V _{CC} Active Current	$f = 5 \text{ MHz}, I_{OUT} = 0 \text{ mA}, \overline{CE} = V_{IL}, V_{CC} = 3.6 \text{V}$		8	mA
		V _{CC} = 3.0 to 3.6V	-0.6	0.8	V
V _{IL}	Input Low Voltage	V _{CC} = 2.7 to 3.6V	-0.6	0.2 x V _{CC}	V
		V _{CC} = 3.0 to 3.6V	2.0	V _{CC} + 0.5	V
V _{IH}	Input High Voltage	V _{CC} = 2.7 to 3.6V	0.7 x V _{CC}	V _{CC} + 0.5	V
		I _{OL} = 2.0 mA		0.4	V
V _{OL}	Output Low Voltage	I _{OL} = 100 μA		0.2	V
		I _{OL} = 20 μA		0.1	V
		I _{OH} = -2.0 mA	2.4		V
V _{OH}	Output High Voltage	I _{OH} = -100 μA	V _{CC} - 0.2		V
		I _{OH} = -20 μA	V _{CC} - 0.1		V
V _{CC} = 4.5V	to 5.5V				
ILI	Input Load Current	$V_{IN} = 0V \text{ to } V_{CC}$		±1	μΑ
I _{LO}	Output Leakage Current	$V_{OUT} = 0V$ to V_{CC}		±5	μA
I _{PP1} ⁽²⁾	V _{PP} ⁽¹⁾ Read/Standby Current	$V_{PP} = V_{CC}$		10	μΑ
		I_{SB1} (CMOS), $\overline{CE} = V_{CC} \pm 0.3V$		100	μΑ
I _{SB}	V _{CC} ⁽¹⁾ Standby Current	I_{SB2} (TTL), \overline{CE} = 2.0 to V_{CC} + 0.5V		1	mA
I _{CC}	V _{CC} Active Current	$f = 5 \text{ MHz}, I_{OUT} = 0 \text{ mA}, \overline{CE} = V_{IL}$		30	mA
V _{IL}	Input Low Voltage		-0.6	0.8	V
V _{IH}	Input High Voltage		2.0	V _{CC} + 0.5	V
V _{OL}	Output Low Voltage	I _{OL} = 2.1 mA		0.4	V
V _{OH}	Output High Voltage	I _{OH} = -400 μA	2.4		V

Notes: 1. V_{CC} must be applied simultaneously with or before V_{PP} and removed simultaneously with or after V_{PP}

2. V_{PP} may be connected directly to V_{CC} , except during programming. The supply current would then be the sum of I_{CC} and I_{PP}

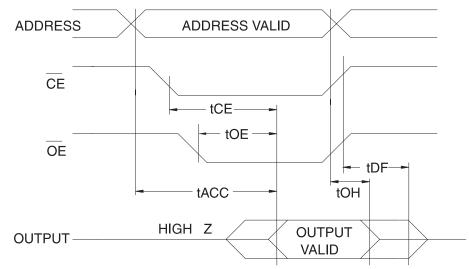
AT27BV1024

AC Characteristics for Read Operation

 V_{CC} = 2.7V to 3.6V and 4.5V to 5.5V

			AT27BV1024						
			-	90	-	12	-	15	
Symbol	Parameter	Condition	Min	Max	Min	Max	Min	Max	Units
t _{ACC} ⁽³⁾	Address to Output Delay	$\overline{CE} = \overline{OE} \\ = V_{IL}$		90		120		150	ns
t _{CE} ⁽²⁾	CE to Output Delay	$\overline{OE} = V_{IL}$		90		120		150	ns
t _{OE} ⁽²⁾⁽³⁾	OE to Output Delay	$\overline{CE} = V_{IL}$		30		35		50	ns
t _{DF} ⁽⁴⁾⁽⁵⁾	\overline{OE} or \overline{CE} High to Output Float, whichever occurred first			30		30		40	ns
t _{OH}	Output Hold from Address, \overline{CE} or \overline{OE} , whichever occurred first		0		0		0		ns

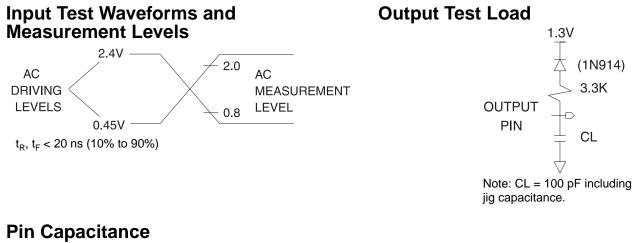
AC Waveforms for Read Operation⁽¹⁾



- Notes: 1. Timing measurement references are 0.8V and 2.0V. Input AC drive levels are 0.45V and 2.4V, unless otherwise specified.
 - 2. \overline{OE} may be delayed up to t_{CE} t_{OE} after the falling edge of \overline{CE} without impact on t_{CE}.
 - 3. \overline{OE} may be delayed up to t_{ACC} t_{OE} after the address is valid without impact on t_{ACC} .
 - 4. This parameter is only sampled and is not 100% tested.
 - 5. Output float is defined as the point when data is no longer driven.
 - 6. When reading a 27BV1024, a 0.1 μ F capacitor is required across V_{CC} and ground to suppress spurious voltage transients.





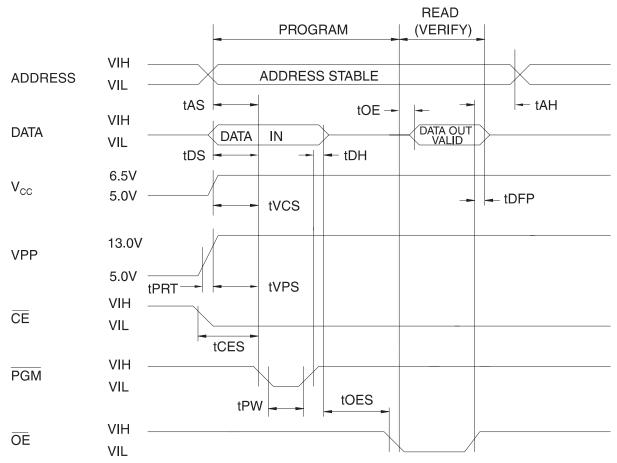


 $f = 1 MHz T = 25^{\circ}C^{(1)}$

Symbol	Тур	Max Units		Conditions
C _{IN}	4	10	pF	$V_{IN} = 0V$
C _{OUT}	8	12	pF	$V_{OUT} = 0V$

Note: 1. Typical values for nominal supply voltage. This parameter is only sampled and is not 100% tested.

Programming Waveforms⁽¹⁾



Notes: 1. The Input Timing Reference is 0.8V for $\rm V_{IL}$ and 2.0V for $\rm V_{IH}$

- 2. t_{OE} and t_{DFP} are characteristics of the device but must be accommodated by the programmer.
- 3. When programming the AT27BV1024 a 0.1 μ F capacitor is required across V_{PP} and ground to suppress spurious voltage transients.

DC Programming Characteristics

TA = 25 \pm 5°C, V_{CC} = 6.5 \pm 0.25V, V_{PP} = 13.0 \pm 0.25V

			Li	mits	
Symbol	Parameter	Test Conditions	Min	Max	Units
ILI	Input Load Current	$V_{IN} = V_{IL}, V_{IH}$		±10	μA
V _{IL}	Input Low Level		-0.6	0.8	V
V _{IH}	Input High Level		2.0	V _{CC} + 0.1	V
V _{OL}	Output Low Voltage	I _{OL} = 2.1 mA		0.4	V
V _{OH}	Output High Voltage	I _{OH} = -400 μA	2.4		V
I _{CC2}	V _{CC} Supply Current (Program and Verify)			50	mA
I _{PP2}	V _{PP} Supply Current	$\overline{CE} = \overline{PGM} = V_{IL}$		30	mA
V _{ID}	A9 Product Identification Voltage		11.5	12.5	V





AC Programming Characteristics

TA = 25 \pm 5°C, V_{CC} = 6.5 \pm 0.25V, V_{PP} = 13.0 \pm 0.25V

			Li		
Symbol	Parameter	Test Conditions ⁽¹⁾	Min	Max	Units
t _{AS}	Address Setup Time		2		μs
t _{CES}	CE Setup Time		2		μs
t _{OES}	OE Setup Time	Input Rise and Fall Times:	2		μs
t _{DS}	Data Setup Time	(10% to 90%) 20 ns	2		μs
t _{AH}	Address Hold Time	Input Pulse Levels:	0		μs
t _{DH}	Data Hold Time	0.45V to 2.4V	2		μs
t _{DFP}	OE High to Output Float Delay ⁽²⁾		0	130	ns
t _{VPS}	V _{PP} Setup Time	Input Timing Reference Level: 0.8V to 2.0V	2		μs
t _{VCS}	V _{CC} Setup Time		2		μs
t _{PW}	PGM Program Pulse Width ⁽³⁾	Output Timing Reference Level:	95	105	μs
t _{OE}	Data Valid from OE	0.8V to 2.0V		150	ns
t _{PRT}	V _{PP} Pulse Rise Time During Programming		50		ns

Notes: 1. V_{CC} must be applied simultaneously or before V_{PP} and removed simultaneously or after V_{PP}

- This parameter is only sampled and is not 100% tested. Output Float is defined as the point where data is no longer driven see timing diagram.
- 3. Program Pulse width tolerance is 100 $\mu sec \pm 5\%.$

Atmel's 27BV1024 Integrated Product Identification Code⁽¹⁾

		Pins				Hex					
Codes	A0	015-08	07	O 6	O5	04	O3	O2	01	00	Data
Manufacturer	0	0	0	0	0	1	1	1	1	0	001E
Device Type	1	0	1	1	1	1	0	0	0	1	00F1

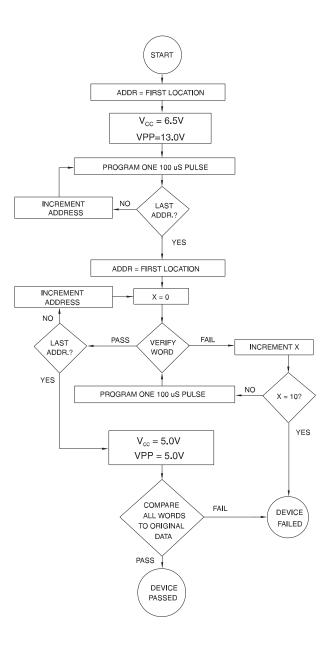
Note: 1. The AT27BV1024 has the same Product Identification Code as the AT27C1024. Both are programming compatible.

AT27BV1024

Rapid Programming Algorithm

A 100 μ s PGM pulse width is used to program. The address is set to the first location. V_{CC} is raised to 6.5V and V_{PP} is raised to 13.0V. Each address is first programmed with one 100 μ s PGM pulse without verification. Then a verification / reprogramming loop is executed for each address. In the event a word fails to pass verification, up to 10 successive 100 μ s pulses are applied with a verification

after each pulse. If the word fails to verify after 10 pulses have been applied, the part is considered failed. After the word verifies properly, the next address is selected until all have been checked. V_{PP} is then lowered to 5.0V and V_{CC} to 5.0V. All words are read again and compared with the original data to determine if the device passes or fails.





Ordering Information

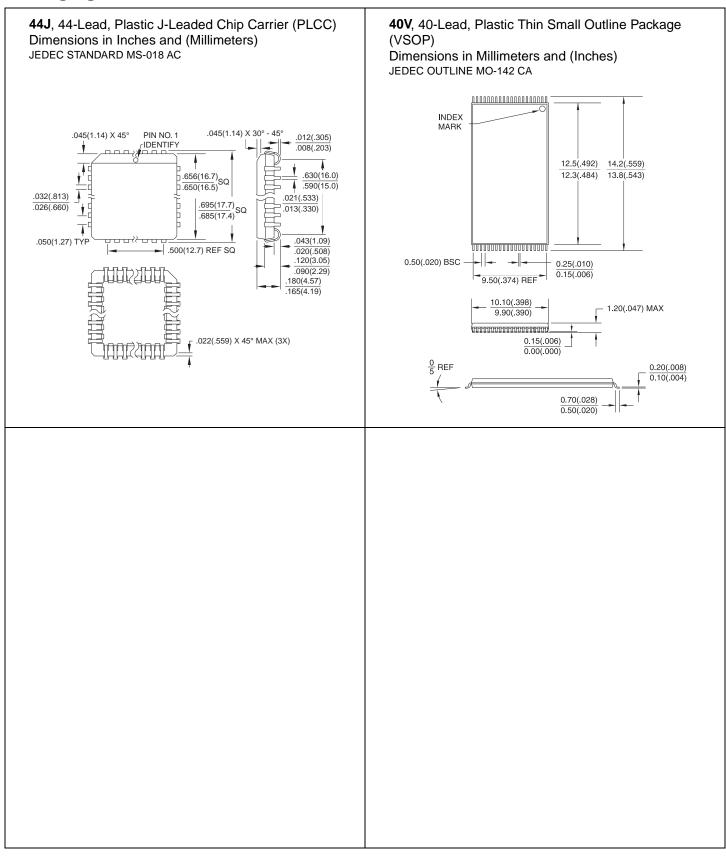
t _{ACC}	ACC I _{CC} (mA)				
(ns)	Active	Standby	Ordering Code	Package	Operation Range
90	8	0.02	AT27BV1024-90JC	44J	Commercial
			AT27BV1024-90VC	40V	(0°C to 70°C)
	8	0.02	AT27BV1024-90JI	44J	Industrial
			AT27BV1024-90VI	40V	(-40°C to 85°C)
120	8 0.02		AT27BV1024-12JC	44J	Commercial
			AT27BV1024-12VC	40V	(0°C to 70°C)
	8	0.02	AT27BV1024-12JI	44J	Industrial
			AT27BV1024-12VI	40V	(-40°C to 85°C)
150	8	0.02	AT27BV1024-15JC	44J	Commercial
			AT27BV1024-15VC	40V	(0°C to 70°C)
	8	0.02	AT27BV1024-15JI	44J	Industrial
			AT27BV1024-15VI	40V	(-40°C to 85°C)

Package Type				
44J	44-Lead, Plastic J-Leaded Chip Carrier (PLCC)			
40V	40-Lead, Plastic Thin Small Outline Package (VSOP) 10 x 14 mm			

AT27BV1024

AT27BV1024

Packaging Information







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